

SBP-8138634033-1212-EP

E-Band Power Amplifier, 81 to 86 GHz, 40 dB Gain, +33 dBm P_{sat}

SBP-8138634033-1212-EP is a E-Band GaN power amplifier with a typical small signal gain of 40 dB and a nominal P_{sat} of +33 dBm across the frequency range of 81 to 86 GHz. The DC power requirement for the amplifier is +28 V_{DC}/0.9 A. The mechanical configurations is an inline structure with WR-12 waveguides and UG-387/U anti-cocking flanges. A Power amplifier module comes with heatsink and fan assembled with the unit.



Electrical Specifications:

Parameter	Minimum	Typical	Maximum
Frequency	81 GHz		86 GHz
Small Signal Gain		40 dB	
Power Gain		35 dB	
P _{sat}		+33 dBm	
P _{in}			+10 dBm
Input Return Loss		10 dB	
Output Return Loss		5 dB	
DC Supply Voltage (VDD)	+26 V _{DC}	+28 V _{DC}	+32 V _{DC}
DC Supply Current		0.9 A	
Supply Voltage to Fan		+12 V _{DC} /0.2 A	
Specification Temperature		+25 °C	
Operating Temperature	0 °C		+50 °C

Mechanical Specifications:

Item	Specification
Input	WR-12 Waveguide with UG-387/U Anti-Coking Flange
Output	WR-12 Waveguide with UG-387/U Anti-Coking Flange
Power Supply	Solder Pin
Case Material	Aluminum
Finish	Gold Plated
Size	3.15" (L) X 2.99" (W) X 3.69" (H)
Outline	BP-HE-H1

ECCN

3A001.b.4

FEATURES

- Class AB GaN Technique
- Broadband Performance
- High Gain
- High Output Power
- Forced Air Cooling
- In-line Port Configuration

APPLICATIONS

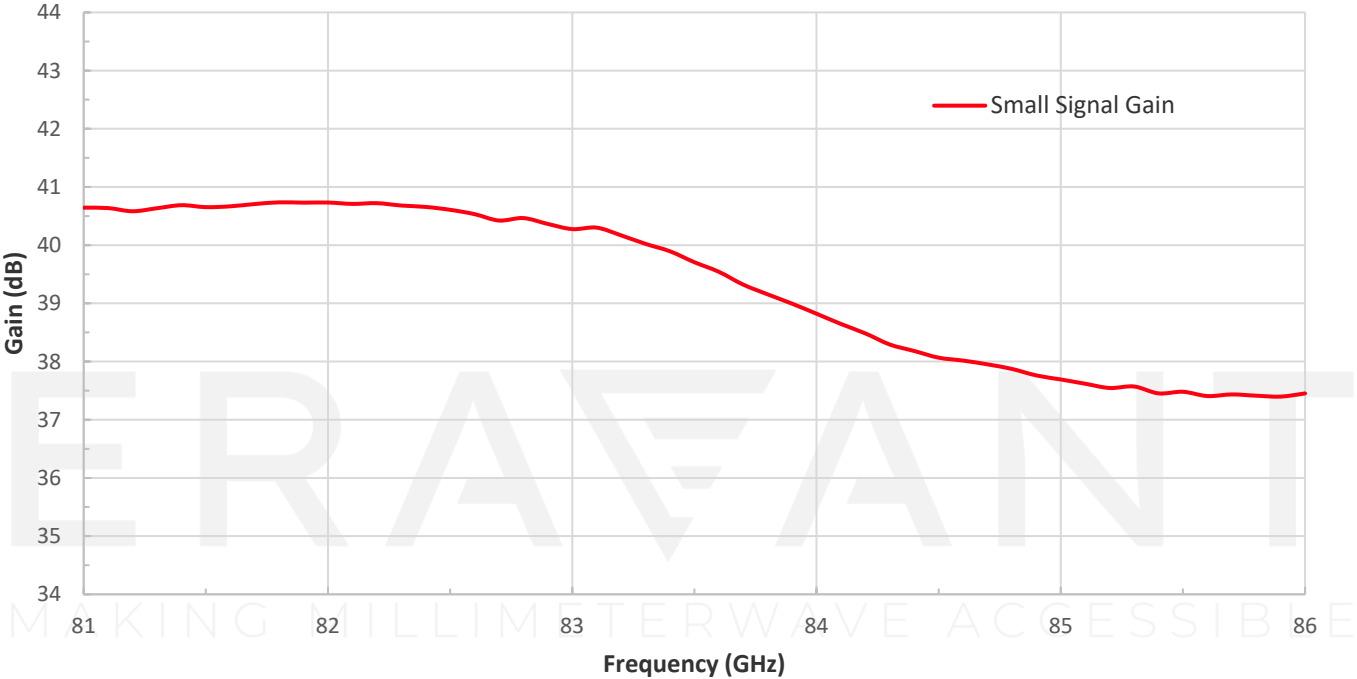
- Radar Systems
- Communication Systems
- Test Equipment

SUPPLEMENTAL DETAILS



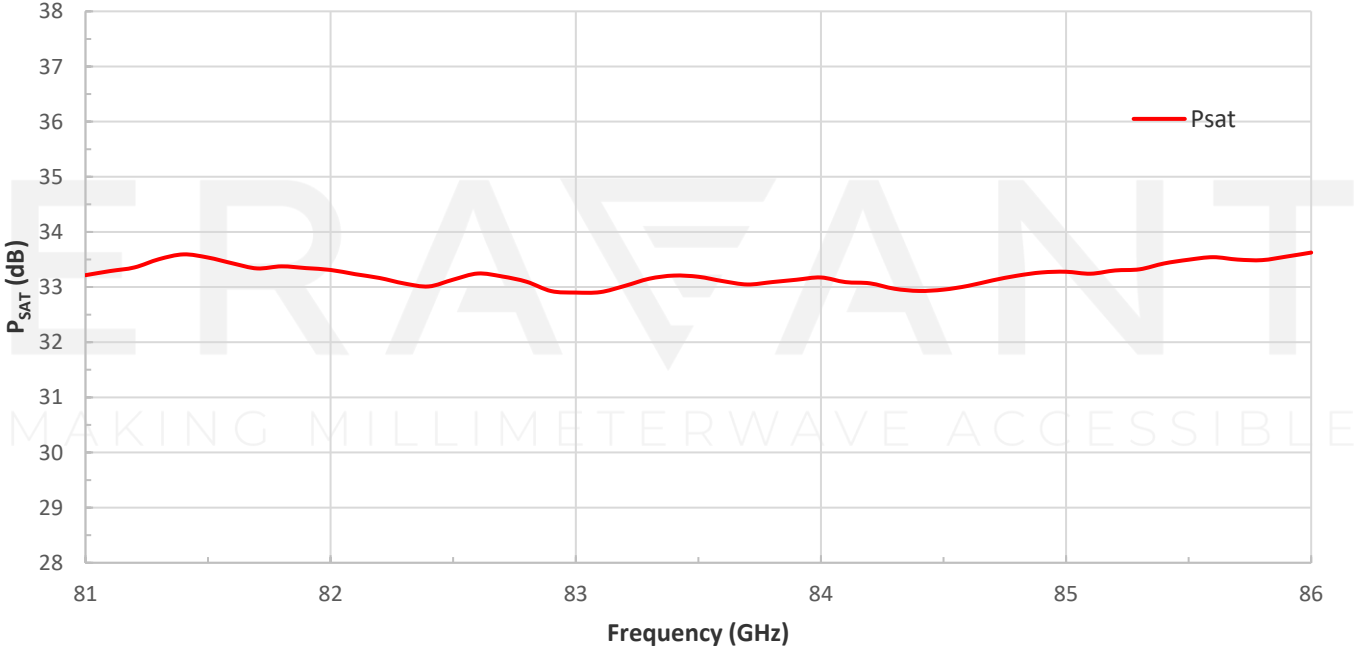
Typical Gain vs. Frequency

Bias: +28 V_{DC}/ 718 mA



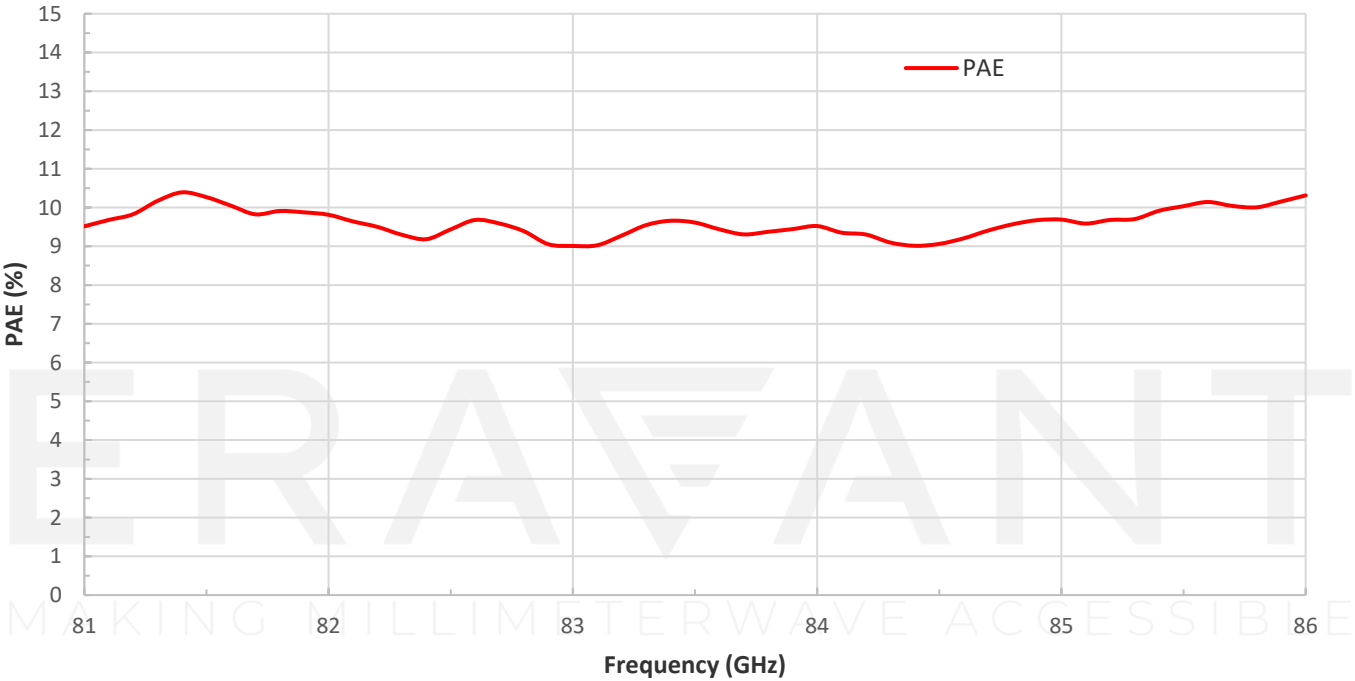
Typical P_{SAT} vs. Frequency

Bias: +28 V_{DC}/ 798 mA



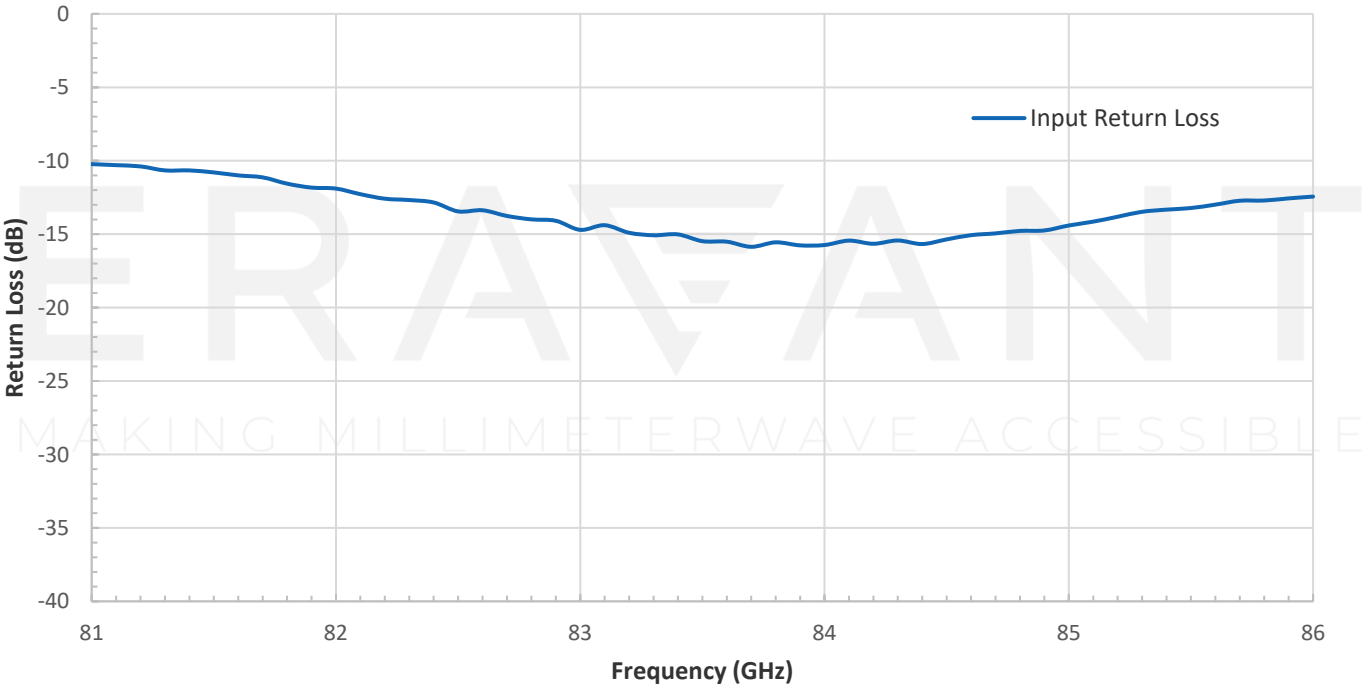
Typical PAE vs. Frequency

Bias: +28 V_{DC}/ 798 mA



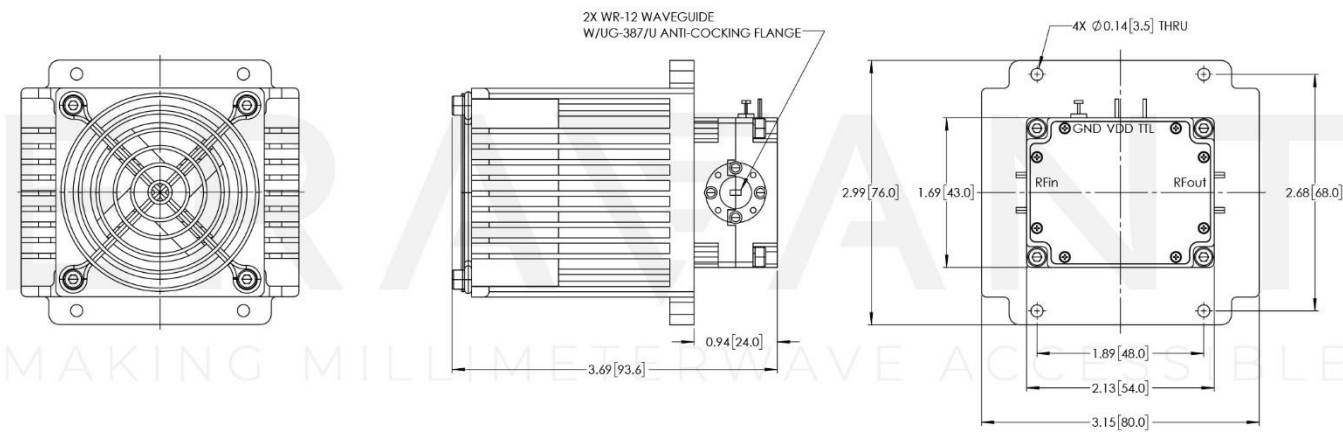
Typical Return Loss vs. Frequency

Bias: +28 V_{DC}/ 718 mA



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Mechanical Outline: (Unless otherwise specified, all dimensions are in inches [millimeters])



WIRE COLOR	FUNCTIONS
RED	+12V
BLACK	GND
YELLOW	TACH SIGNAL (OPTIONAL)
BLUE	PWM (OPTIONAL)

NOTE:

- All data presented is collected from a sample lot. Actual data may vary unit to unit.
- All testing was performed under +25 °C case temperature.
- Other mechanical configurations are available under different model numbers.
- Eravant reserves the right to change the information presented without notice.

CAUTION:

- Exceeding absolute maximum ratings shown will damage the device.
- Do not block the air inlets and outlets.
- The device is static sensitive. Always follow ESD rules when working with the device.
- Do not plug or unplug any connectors when amplifier is activated. All connectors must be connected/disconnected when amplifier is off.
- The case temperature of the device shall never exceed +50 °C. Use proper heatsink or fan if necessary
- Any foreign objects in the waveguide will degrade performance and/or damage the device.